

SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Thick Film chip RESISTOR

- Samsung P/N: RC1005J***CS
- Description :
- 1005, ±5%, (1Ω~10㎞), 1/16W

A. Samsung Part Number

	RC 1005 J **** CS ① ② ③ ④ ⑤		
① Code designation	Samsung Thick - Film Chip Resistor		
② Dimension	1005 (mm code) L: 1.0 ±0.05 mm W: 0.5 ±0.05 mm T: 0.35 ±0.05 mm		
③ Resistancs tolerance	±5 %		
Nominal resistance value	** 3digits Left 2 digits : Resistance value, Right 1 digits : Exponential number of 10. ex) $101 : 10 \times 10^1 = 10 \times 10 = 100\Omega$ ** 4digits Left 3 digits : Resistance value, Right 1 digits : Exponential number of 10. ex) $4222 : 422 \times 10^2 = 422 \times 100 = 42.2 k\Omega$ Read alphabet "R" as decimal point "000" : Jumper(0 Ω) ex) $3R7 : 3.7 = 3.7\Omega / 88R7 : 88.7 = 88.7\Omega$		
5 Packing code	7" Reel packaging		

B. Samsung Reliablility Test and Judgement condition

	Judgement		Test condition	
	Resistor	Jumper	Resistor	Jumper
Direct Current	Within the regulated resistance	50mΩ Max	Voltage apply Within 5 sec	
Resistance	tolerance.			
Short-time	Less than $\pm(1\%+0.1\Omega)$ of the initial value	50mΩ Max	Apply 2.5 times rated voltage for 5sec	Max Surge
Overload	No evidence of mechanical damage			Current
Intermittent	Less than $\pm(3\%+0.1\Omega)$ of the initial value	50mΩ Max	2.5 times of rated voltage.	Max Surge
Overload	No evidence of mechanical damage		1 sec On, 25 sec Off / 10,000cycles	Current
Dielectric	No evidence of mechanical damage		Apply Voltage for 1minute	
Withstanding Voltage			0603:50v	
Insulation	Over 1,000MΩ		1005,1608:100v	
Resistance			Other: 500v	
	■ J-Grade		Test Temperature(°C) 20°C→-55°C/20°C→1	25℃
Temperature	1Ω≤R<10Ω:+300/-200ppm/ ິC		T.C.R(ppm/°C) = $R - R_0 = 1$	06
Characteristic	10Ω≤R≤1MΩ:±100ppm/ິC(0603±250ppm)		T.C.R(ppm/°C) = $\frac{R - R_0}{R_0} \times \frac{1}{T - T_0} \times 1$	0
	1MΩ <r≤10mω:±300ppm td="" ຶc<=""><td></td><td></td><td></td></r≤10mω:±300ppm>			
	■ F-Grade		T₀: 20 ± 2 ℃, R0 : Resistance at	ΓΟ (Ω)
	10Ω≤R≤1MΩ:±100ppm/℃(0603±250ppm)		T : Test temperature , R : Resistance	e at T (Ω)
Solderability	Coverage: $95\% \leq$ each termination.		Solder Temp : 245 °C	
			Dipping time : 3 sec	

	Judgement		Test condition
Bending test	Less than $\pm (0.5\% + 0.05\Omega)$ of the initial value	e 50mΩ Max	3mm of bending shall be applied
	No evidence of mechanical damage		for 5sec.
Adhesive strength	No mechanical damage or sign of disconnection		Test strengh : 5N
of termination			Test time: Applying pressure for 10seconds
Resistance to	Less than $\pm(1\%+0.05\Omega)$ of the initial value	50mΩ Max	260±5℃ , 10 sec
soldering heat	No evidence of mechanical damage		
Anti-Vibration	Less than $\pm(1\%+0.05\Omega)$ of the initial value	50mΩ Max	Test amplitude : 1.5mm
test	No evidence of mechanical damage		Frequency 10Hz -55 Hz -10 Hz / 2hr in x,y,z direction.
Temperature	Less than $\pm(1\%+0.1\Omega)$ of the initial value	50mΩ Max	100cycles, -55 ℃/30min ↔125 ℃/30min
cycle	No evidence of mechanical damage		sweep time:5min
Load life	Less than $\pm(3\%+0.1\Omega)$ of the initial value	50mΩ Max	Test voltage: rated voltage / 70±2 ℃
	No evidence of mechanical damage		1,000hours(90min:On , 30min:Off)
Low Temp.	Less than $\pm(3\%+0.1\Omega)$ of the initial value	50mΩ Max	Dwell in -55 $^\circ\!\!\!\mathrm{C}$ chamber without loading
Exposure	No evidence of mechanical damage		for 1,000hours
High Temp	Less than $\pm(3\%+0.1\Omega)$ of the initial value	50mΩ Max	Dwel in 125 $^{\circ}$ C or 155 $^{\circ}$ C chamber without loading
Exposure	No evidence of mechanical damage		for 1,000hours
Moisture	Less than $\pm(3\%+0.1\Omega)$ of the initial value	50mΩ Max	Test voltage: rated voltage / 40±2 °C
Resistance	No evidence of mechanical damage		1,000hours(90min:On,30min:Off) / 90~95% RH

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 °C, 10sec. Max)

* For the more detail Specification, Please refer to the samsung chip RESISTOR catalogue.